

SILICON TRANSISTOR NE68039 / 2SC4095 JEITA Part No.

MICROWAVE LOW NOISE AMPLIFIER NPN SILICON EPITAXIAL TRANSISTOR 4 PINS MINI MOLD

DESCRIPTION

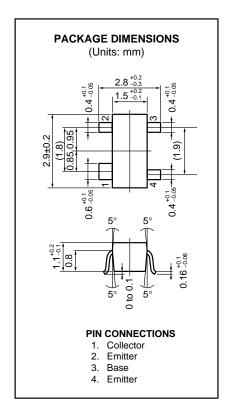
The NE68039 / 2SC4095 is an NPN epitaxial silicon transistor designed for use in low-noise and small signal amplifiers from VHF band to UHF band. NE68039 / 2SC4095 features excellent power gain with very low-noise figures. NE68039 / 2SC4095 employs direct nitiride passivated base surface process (DNP process) which is a proprietary new fabrication technique which provides excellent noise figures at high current values. This allows excellent associated gain and very wide dynamic range.

FEATURES

- NF = 1.8 dB TYP. @ f = 2.0 GHz, VcE = 6 V, Ic = 5 mA
- $|S_{21e}|^2 = 9.5 \text{ dB TYP.}$ @ f = 2.0 GHz, VcE = 6 V, Ic = 10 mA

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Collector to Base Voltage	Vсво	20	V
Collector to Emitter Voltage	VCEO	10	V
Emitter to Base Voltage	VEBO	1.5	V
Collector Current	Ic	35	mΑ
Total Power Dissipation	Рт	200	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-65 to +150	°C



ELECTRICAL CHARACTERISTICS (TA = 25 °C)

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CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	Ісво			1.0	μА	Vcb = 10 V, IE = 0
Emitter Cutoff Current	Ієво			1.0	μА	V _{EB} = 1 V, I _C = 0
DC Current Gain	hfe	50	100	250		Vce = 6 V, Ic = 10 mA
Gain Bandwidth Product	f⊤		10		GHz	Vce = 6 V, Ic = 10 mA f = 1.0 GHz
Feed-Back Capacitance	Cre		0.25	0.8	pF	VcB = 10 V, IE = 0, f = 1.0 MHz
Insertion Power Gain	S _{21e} ²	7.5	9.5		dB	Vce = 6 V, Ic = 10 mA, f = 2.0 GHz
Maximum Available Gain	MAG		12		dB	Vce = 6 V, Ic = 10 mA, f = 2.0 GHz
Noise Figure	NF		1.8	3.0	dB	Vce = 6 V, Ic = 5 mA, f = 2.0 GHz

hfe Classification

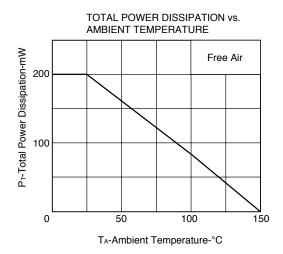
Class	R46/RDF *	R47/RDG *	R48/RDH *
Marking	R46	R47	R48
hfe	50 to 100	80 to 160	125 to 250

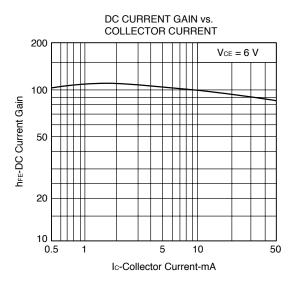
* Old Specification / New Specification

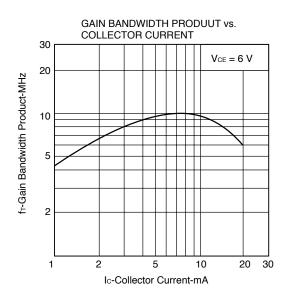
Document No. P10367EJ2V1DS00 (2nd edition)

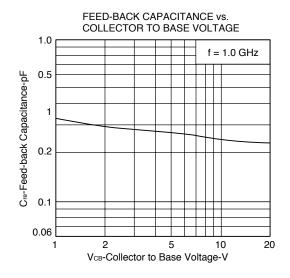
Date Published March 1997 N

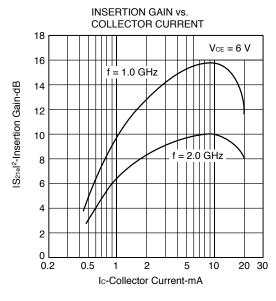
TYPICAL CHARACTERISTICS (TA = 25 °C)

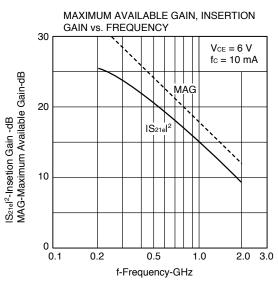


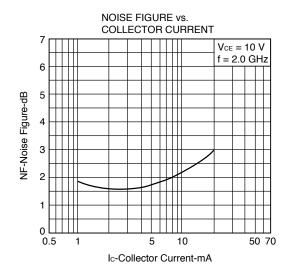












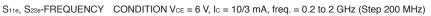
S-PARAMETER

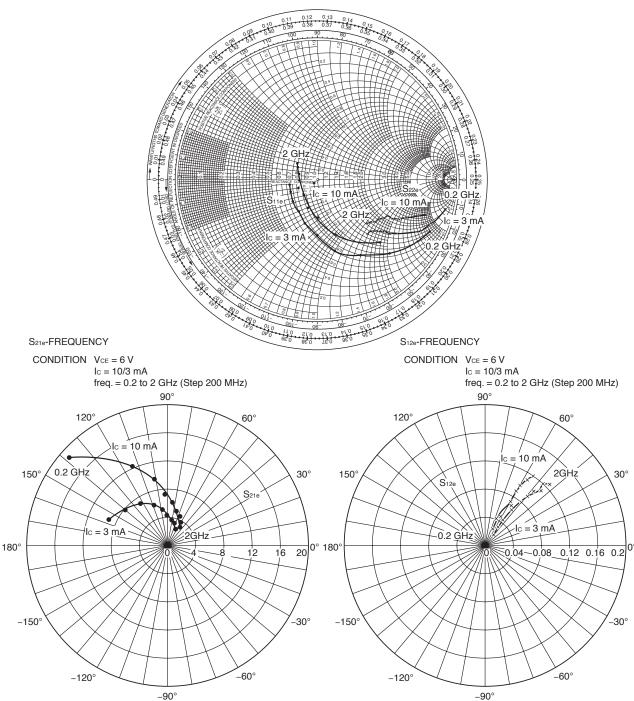
 \mbox{Vce} = 6.0 V, Ic = 3.0 mA, Zo = 50 Ω

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f (MHz)	S ₁₁	∠ S11	S ₂₁	∠ S ₂₁	S ₁₂	∠ S12	S ₂₂	∠ S 22
200	0.870	-24.2	9.193	155.6	0.031	53.6	0.946	-12.8
400	0.747	-44.6	7.780	136.6	0.040	66.2	0.876	-20.7
600	0.628	-59.8	7.058	122.1	0.064	54.7	0.816	-26.4
800	0.516	- 75.1	5.675	109.4	0.066	56.0	0.743	-30.9
1000	0.400	- 87.7	5.180	99.6	0.090	49.4	0.689	-33.0
1200	0.327	-103.4	4.269	89.8	0.084	47.9	0.654	- 35.7
1400	0.262	– 118.7	3.950	81.7	0.106	48.5	0.604	- 37.7
1600	0.231	-135.5	3.406	74.0	0.105	42.1	0.581	- 41.5
1800	0.205	- 155.3	3.290	66.4	0.126	46.4	0.548	-43.9
2000	0.196	- 170.6	2.867	60.8	0.124	40.9	0.529	-47.1
Vce 6.0 V, Ic = 10.0 mA, Zo = 50 Ω								

f (MHz)	S ₁₁	∠ S ₁₁	S ₂₁	∠ S 21	S ₁₂	∠ S ₁₂	S ₂₂	∠ S 22
200	0.671	-43.5	18.685	137.9	0.023	52.1	0.832	-19.0
400	0.458	-68.7	12.702	115.2	0.029	62.2	0.710	-23.9
600	0.319	-83.7	9.895	102.8	0.046	54.4	0.649	-26.0
800	.0239	-101.9	7.275	92.3	0.049	63.1	0.600	- 27.5
1000	0.172	-119.3	6.261	85.1	0.067	58.6	0.578	-28.4
1200	0.149	-141.4	5.038	77.4	0.070	57.9	0.559	-30.3
1400	0.131	-163.0	4.597	71.0	0.088	56.1	0.527	-32.5
1600	0.132	179.6	3.927	64.8	0.094	54.0	0.514	-35.7
1800	0.150	160.0	3.743	58.8	0.113	55.3	0.494	-38.1
2000	0.163	150.1	3.233	54.5	0.115	50.0	0.478	-41.6

S-PARAMETER





RECOMMENDED SOLDERING CONDTITIONS

The following conditions (see table below) must be met then soldering this product. Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different contions.

TYPES OF SURFACE MOUNT DEVICE

For more details, refer to our document "SMT MANUAL" (IEI-1207).

NE68039 / 2SC4095

Soldering process		Symbol	
Infrared ray reflow	Peak package's surface temp Reflow time: Number of reflow process:	IR30-00-1	
VPS	Peak package's surface temp Reflow time: Number of reflow process:	perature: 215 °C or below, 40 seconds or below (200 °C or higher), 1, Exposure limit*: None	VP15-00-1
Wave soldering	Solder temperature: Flow time: Number of reflow process:	260 °C or below, 10 seconds or below, 1, Exposure limit*: None	WS60-00-1
Partial heating method	Terminal temperature: Flow time: Exposure limit*:	300 °C or below, 3 seconds or below, None	0

^{*:} Exposure limit before soldering after dry-pack package is opened.

Storage conditions: 25 °C and relative humidity at 65 % or less.

Note: Do not apply more than a single process at once, except for "Partial heating method".

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